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# ***Graphene under uni-axial strain and 2D layered organic material $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub> – the physics of tilted Dirac cones***



CENTRE NATIONAL  
DE LA RECHERCHE  
SCIENTIFIQUE

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**PARIS-SUD 11**

PRB **78**, 045415 (2008); EPL **85**, 57005 (2009);  
PRB **80**, 153412 (2009) and EPJB **72**, 509 (2009)

# Outline of the Talk

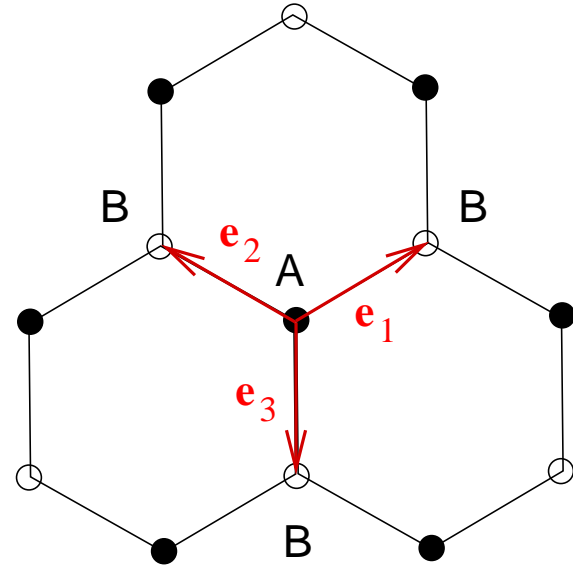
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- **Introduction** to Dirac fermions in **graphene** and  $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>
- Physical origin of **tilted Dirac cones** (example of distorted graphene)
- Motion of Dirac points and **topological (semi-)metal-insulator transition**
- (Tilted) Dirac cones in a **strong magnetic field**
  - reminder of graphene and effect of the tilt
  - **crossed electric and magnetic fields** in graphene and  $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>
  - LL quantisation in the vicinity of the topological phase transition

# Graphene bandstructure *papers from the '50ies*

- Tight-binding model ( $\pi$ -electron nn hopping)

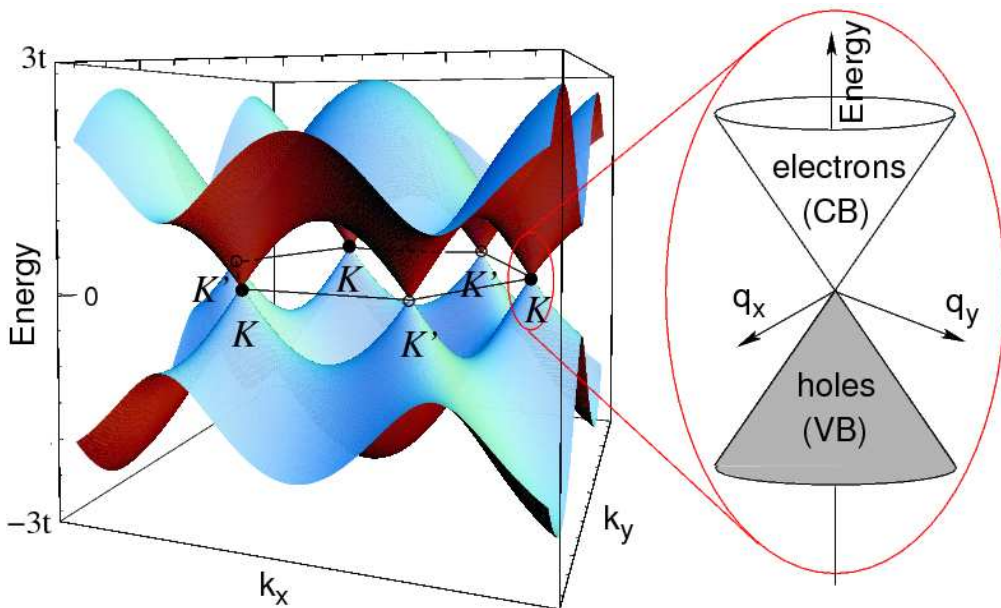
$$H_0 = -t \sum_{i \in A} \sum_{j=1}^3 \left( b_{\mathbf{R}_i + \mathbf{e}_j}^\dagger a_{\mathbf{R}_i} + \text{H.c.} \right)$$



reciprocal-space Hamiltonian  
(A-B sublattice basis):

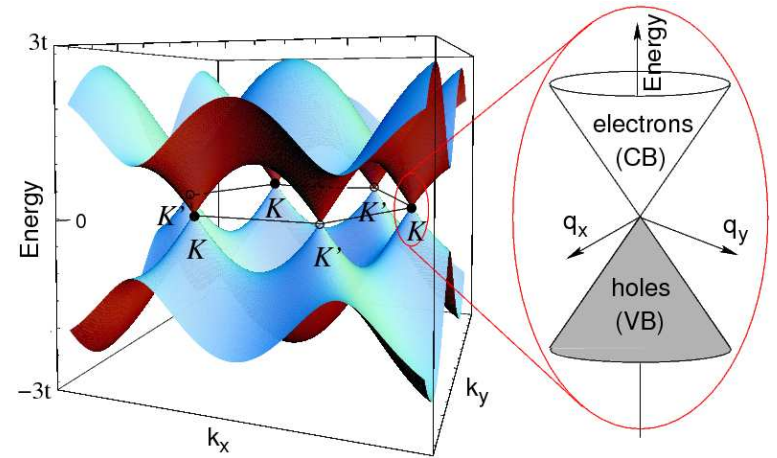
$$H_0 = t \begin{pmatrix} 0 & \gamma_{\mathbf{k}}^* \\ \gamma_{\mathbf{k}} & 0 \end{pmatrix}$$

$$\gamma_{\mathbf{k}} = \sum_j \exp(-i\mathbf{k} \cdot \mathbf{e}_j)$$



# Dirac fermions

- Zero-energy states ( $\varepsilon_{\mathbf{K}^\pm} = 0$ ):  
at  $K$  and  $K'$  points of the 1st BZ



- Continuum limit  $\mathbf{k} = \mathbf{K}^\pm + \mathbf{q}$  with  $|\mathbf{q}| \ll 1/a$ :

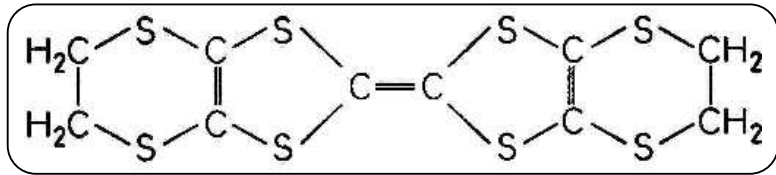
$$\mathcal{H}^{\xi=\pm}(\mathbf{q}) = \xi \frac{3}{2} ta \begin{pmatrix} 0 & q_x - iq_y \\ q_x + iq_y & 0 \end{pmatrix} = \xi \hbar v_F \boldsymbol{\sigma} \cdot \mathbf{q}$$

## 2D Dirac Hamiltonian for massless particles

- Energy dispersion (two-fold valley degeneracy  $\xi = \pm$ ):

$$\varepsilon_{\lambda=\pm, \mathbf{q}}^{\xi=\pm} = \pm \hbar v_F |\mathbf{q}|$$

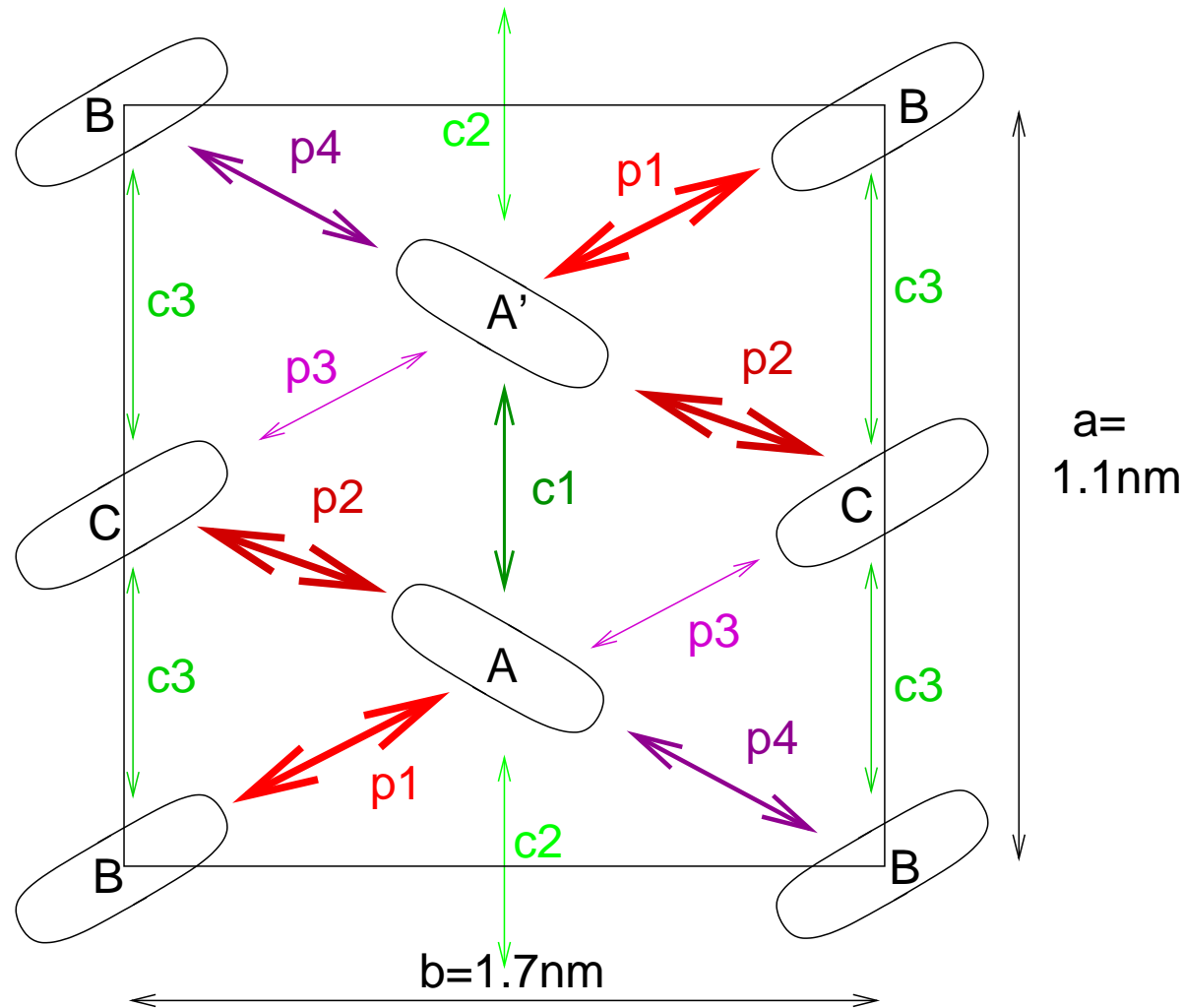
# $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>: crystal structure



BEDT-TTF

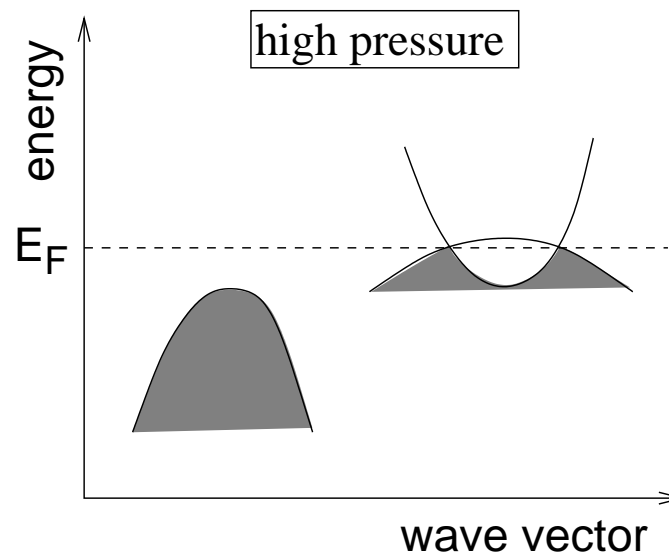
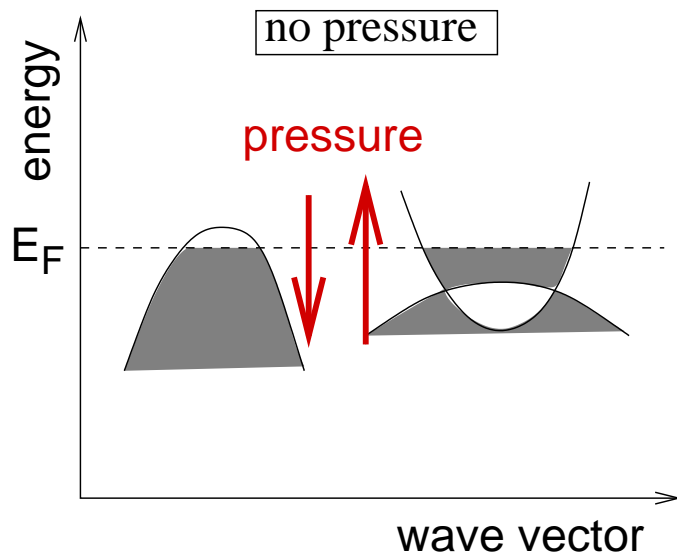
=bis(ethylenedithio)tetrathiafulvalene

- quasi-2D (stacked layers)
- 4 molecules/unit cell  
→  $4 \times 4$  Hamiltonian
- electronic filling:  $3/4$
- $t_i \sim 20 \dots 140$  meV

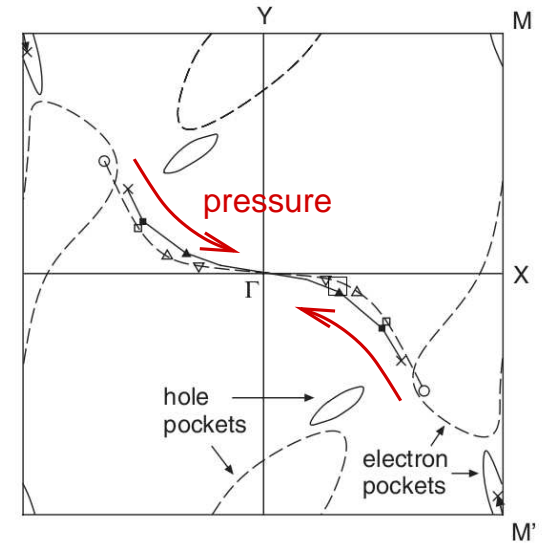


# $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>: electronic band structure

schematic view on upper two bands



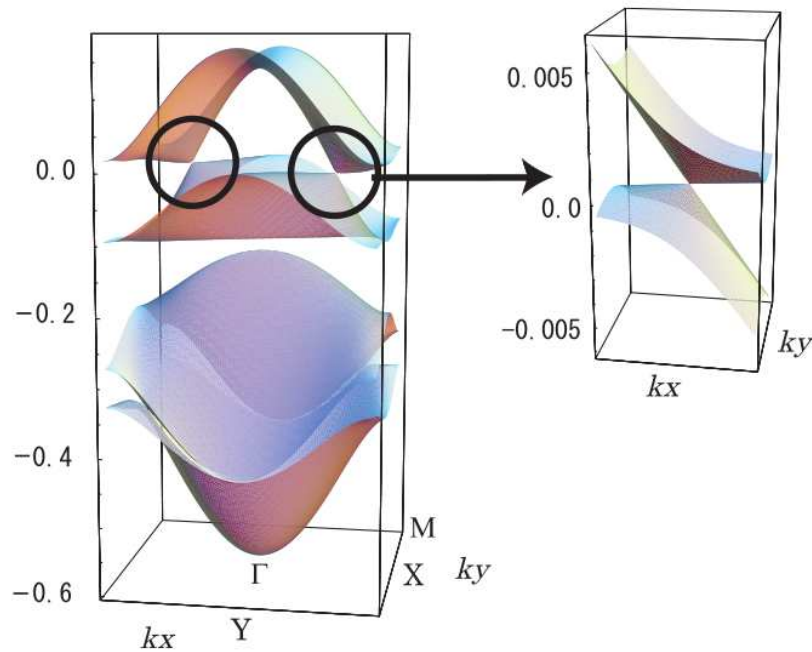
Brillouin zone



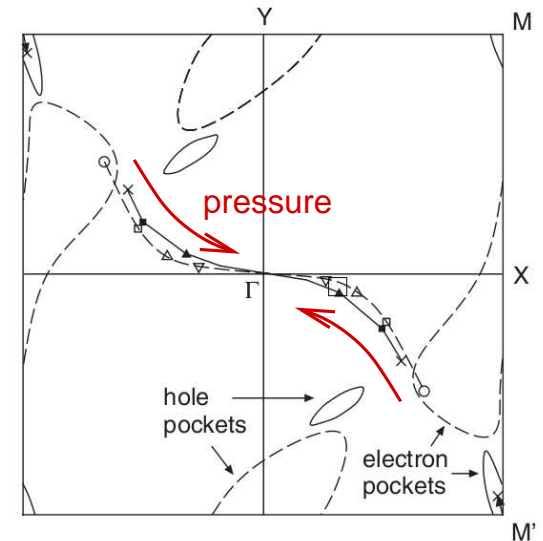
Katayama, Kobayashi, Suzumura, J. Phys. Soc. Japan 75, 054705 (2006)

# $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>: electronic band structure

energy bands under pressure



Brillouin zone



Katayama, Kobayashi, Suzumura, J. Phys. Soc. Japan 75, 054705 (2006)

Complication due to **strong correlations** !

→ **charge ordering** at  $p = 0$  and  $T = 0$

# Correlation effects in $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub> and graphene

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- extended Hubbard model:

$$U \simeq 0.4 \text{ eV} \simeq 3t_{max}, \quad V_c \simeq 0.17 \text{ eV}, \quad V_p \simeq 0.05 \text{ eV}$$

$U$ : onsite repulsion

$V_p, V_c$ : nearest neighbour repulsion

- “fine-structure constant” in continuum model:

$$r_s = \frac{e^2}{\hbar\epsilon v_F} \simeq 20/\epsilon \simeq 10 r_s^{\text{graphene}}$$

$v_F \sim t \times a \simeq 0.1 v_F^{\text{graphene}}$ : average Fermi velocity

⇒ bare correlations in  $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>  $\sim$  10 times larger than in graphene



# Correlations and Dirac points – screening

- (static) RPA screening:

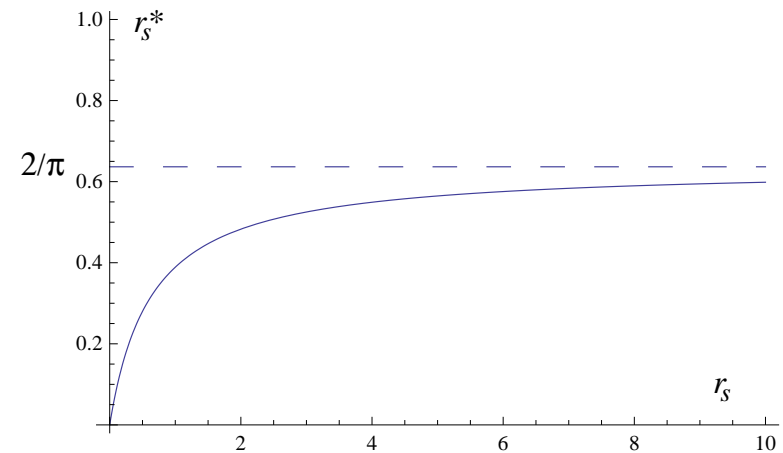
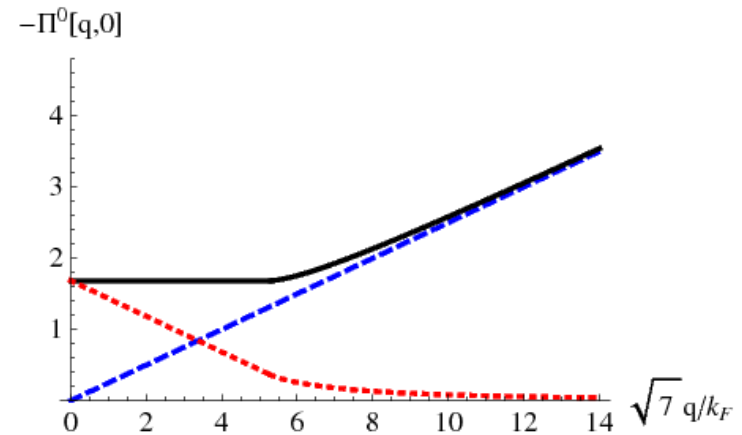
$$\epsilon^{\text{RPA}}(\mathbf{q}) = 1 - \frac{2\pi e^2}{\epsilon q} \Pi^0(\mathbf{q})$$

- bare polarisability:  
two contributions

$$\Pi^0(\mathbf{q}) = \Pi^{\text{vac}}(\mathbf{q}) + \Pi^{\text{dop}}(\mathbf{q})$$

- interband contribution  
absorbed in  $\epsilon \rightarrow \epsilon\epsilon_\infty$

$$r_s^* = \frac{r_s}{\epsilon_\infty} = \frac{r_s}{1 + \pi r_s / 2}$$



Thomas-Fermi type argument valid only for finite doping !

# Generalised Weyl Hamiltonian

Most general 2D Hamiltonian ( $2 \times 2$  matrix) with linear dispersion (**generalised Weyl Hamiltonian**):

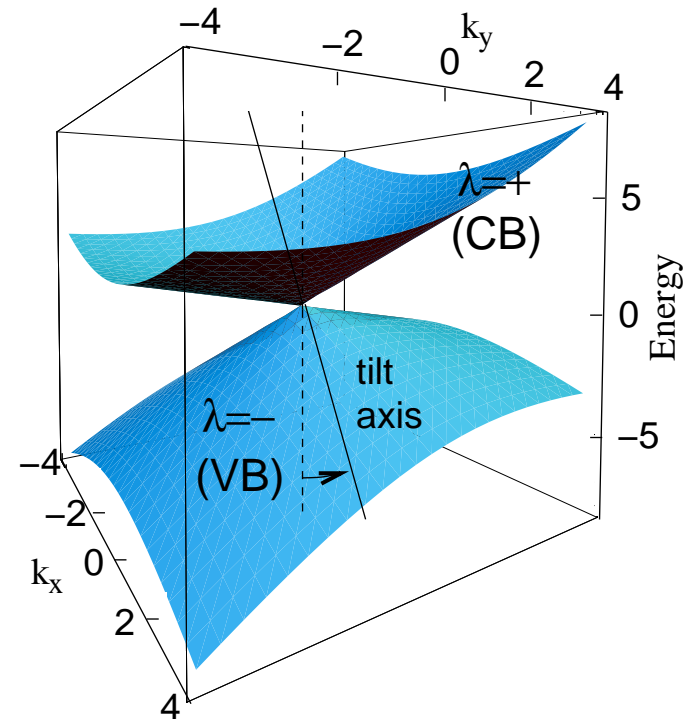
$$H = \sum_{\mu=0}^3 \hbar \mathbf{v}_{\mu} \cdot \mathbf{q} \sigma^{\mu} \quad (\sigma^0 = \mathbb{1}, \sigma^1 = \sigma^x, \sigma^2 = \sigma^y, \sigma^3 = \sigma^z)$$
$$\hat{=} \hbar (\mathbf{w}_0 \cdot \mathbf{q} \mathbb{1} + w_x q_x \sigma^x + w_y q_y \sigma^y)$$

Energy dispersion ( $\hbar \equiv 1$ ,  $\lambda = \pm$ ):

$$\epsilon_{\lambda}(\mathbf{q}) = \mathbf{w}_0 \cdot \mathbf{q} + \lambda \sqrt{w_x^2 q_x^2 + w_y^2 q_y^2}$$

$\mathbf{w}_0$ : “tilt velocity”

Graphene:  $\mathbf{w}_0 = 0$ ,  $w_x = w_y = v_F$



# How to obtain tilted Dirac cones?

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- In graphene:  $\sigma$  denotes  $A - B$  sublattice isospin
- Term proportional to  $\mathbb{1}$ : nnn hopping ( $A \leftrightarrow A, B \leftrightarrow B$ )

⇒ In continuum limit:

$$H_{\text{diag}} = \frac{9}{4} t_{nnn} |\mathbf{q}|^2 a^2 \mathbb{1}$$

i.e. not linear in  $\mathbf{q}$ , but quadratic

- Reason: Dirac points [ $\epsilon(\mathbf{q}_D) = 0$ ] coincide with  $K, K'$  (points of high crystallographic symmetry)

⇒ Drag Dirac points away from  $K, K'$  !

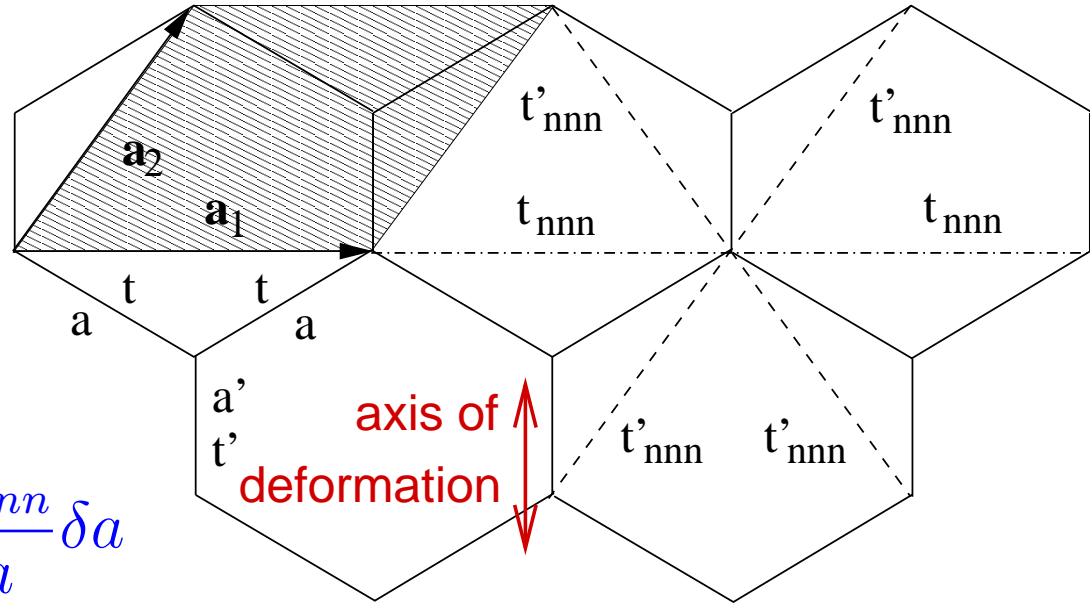
# Graphene under strain (I)

Distortion:

$$a \rightarrow a' = a + \delta a$$

$$t \rightarrow t' = t + \frac{\partial t}{\partial a} \delta a$$

$$t_{nnn} \rightarrow t'_{nnn} = t_{nnn} + \frac{\partial t_{nnn}}{\partial a} \delta a$$

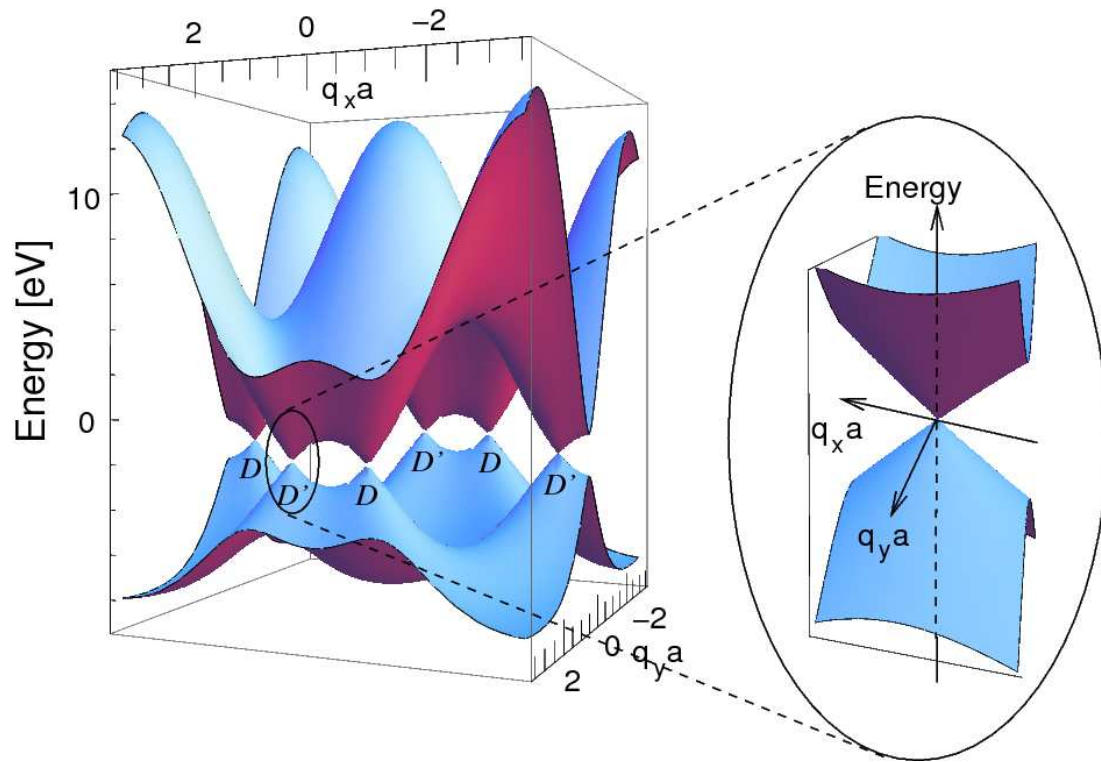


Dirac points move from  $K, K'$  to:

$$q_y^D = 0, \quad q_x^D a = \xi \frac{2}{\sqrt{3}} \arccos \left( -\frac{t'}{2t} \right)$$

$\xi$ : valley index

# Graphene under strain (II)



Estimation of tilt:

$$\tilde{\omega}_0 \equiv \sqrt{\left(\frac{\omega_{0x}}{\omega_x}\right)^2 + \left(\frac{\omega_{0y}}{\omega_y}\right)^2}$$

$$\simeq 0.6 \frac{\delta a}{a}$$

$0 \leq \tilde{\omega}_0 < 1$ :  
“tilt parameter”

$\Rightarrow$  Effect linear in  $\delta a/a$  !

# Dirac-point motion and topological phase transition

Dirac points located at:

$$q_y^D = 0, \quad q_x^D a = \xi \frac{2}{\sqrt{3}} \arccos \left( -\frac{t'}{2t} \right)$$

– topological PT at  $t' = 2t$   
(semi-metal/insulator)

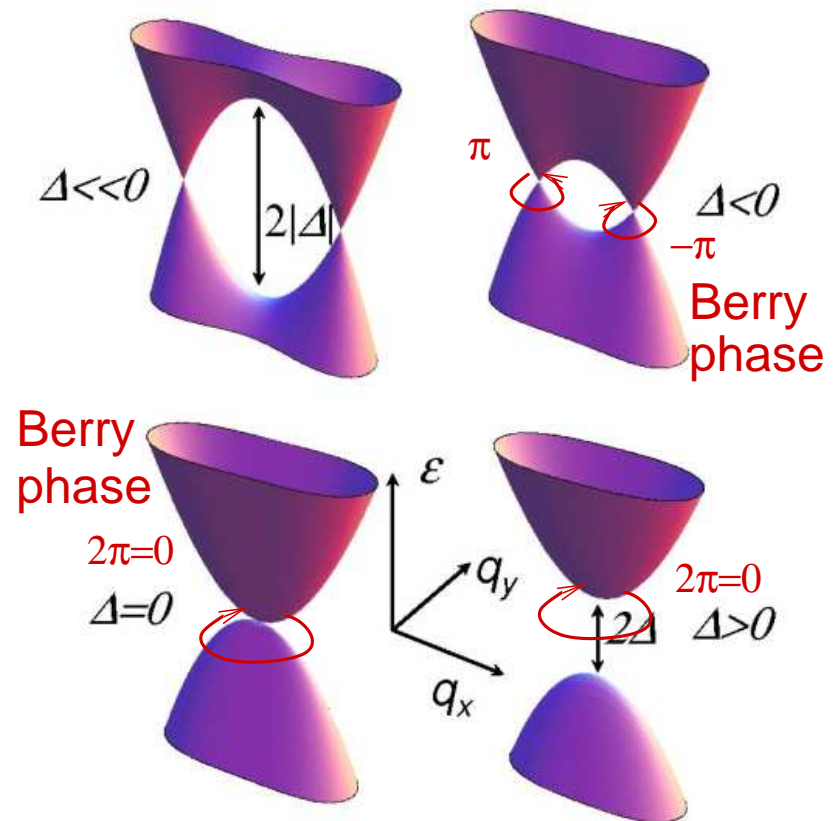
– effective Hamiltonian:

$$H' = \begin{pmatrix} 0 & \Delta + \frac{q_x^2}{2m^*} - icq_y \\ \Delta + \frac{q_x^2}{2m^*} + icq_y & 0 \end{pmatrix}$$

Montambaux, Piéchon, Fuchs, MOG, PRB **80**, 1534012 (2009)

– linear-quadratic dispersion at  $t' = 2t$

Dietl, Piéchon, Montambaux, PRL **100**, 236405 (2008)



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# Dirac Cones in a Strong Magnetic Field

Relativistic Landau levels

# Graphene Landau levels

- Magnetic field ( $B\mathbf{e}_z = \nabla \times \mathbf{A}$ ) via Peierls substitution:

$$\mathbf{q} \rightarrow -i\nabla + e\mathbf{A}$$

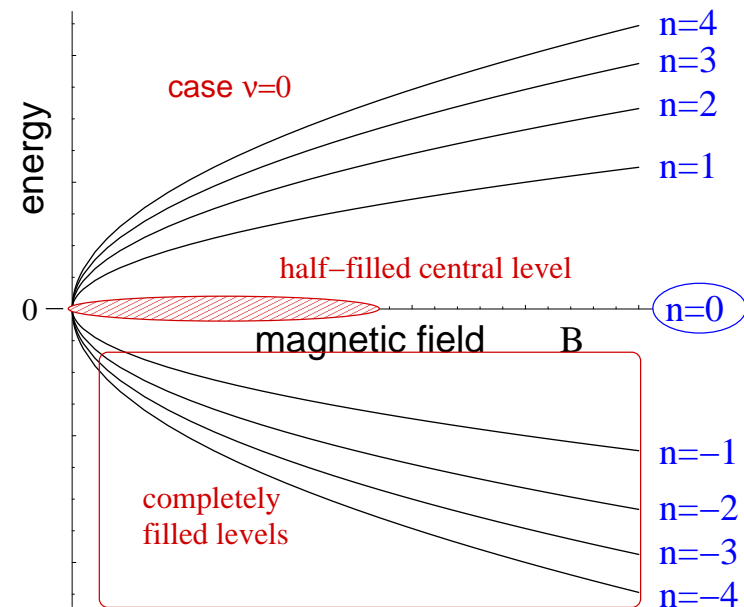
(semiclassical:  $\varepsilon(\mathbf{q}) \rightarrow \varepsilon(\sqrt{2n}/l_B)$ ,  $l_B = 1/\sqrt{eB}$ )

- Energy dispersion with magnetic field (degenerate in valley isospin  $\xi$ ):

$$\varepsilon_{\lambda,n} = \lambda \frac{v_F}{l_B} \sqrt{2|n|} \propto \sqrt{B|n|}$$

(Relativistic LLs)

- Quantum Hall effect at  $\nu = \pm 2, \pm 6, \pm 10, \dots$





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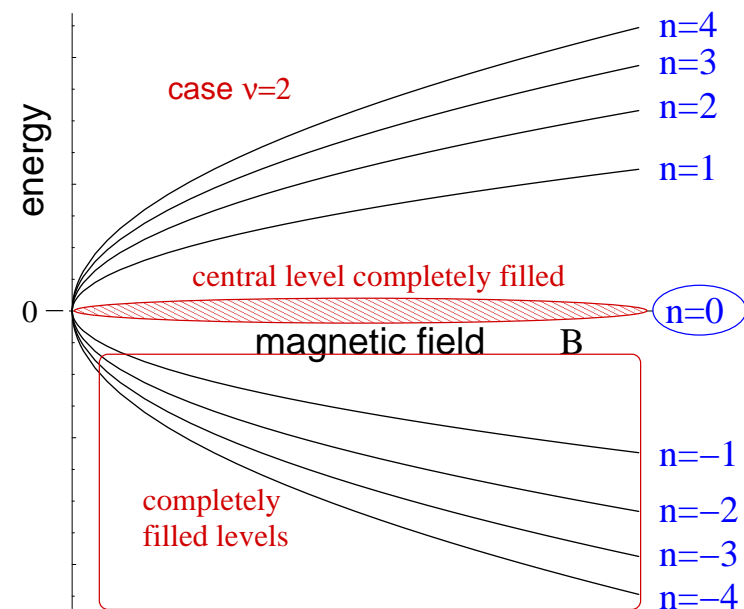
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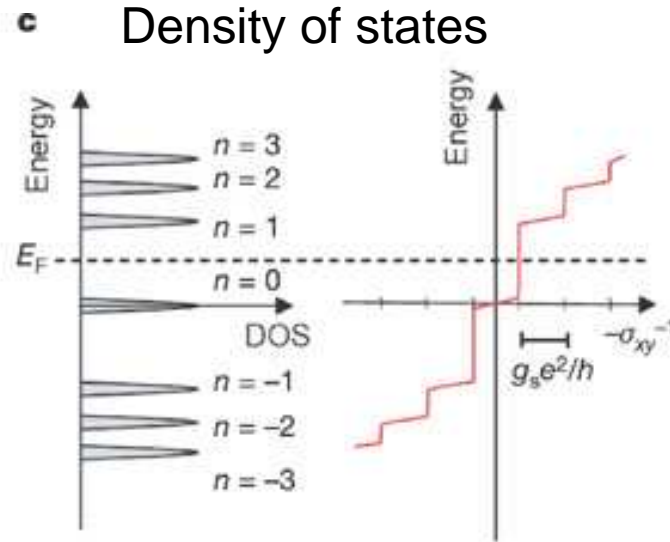
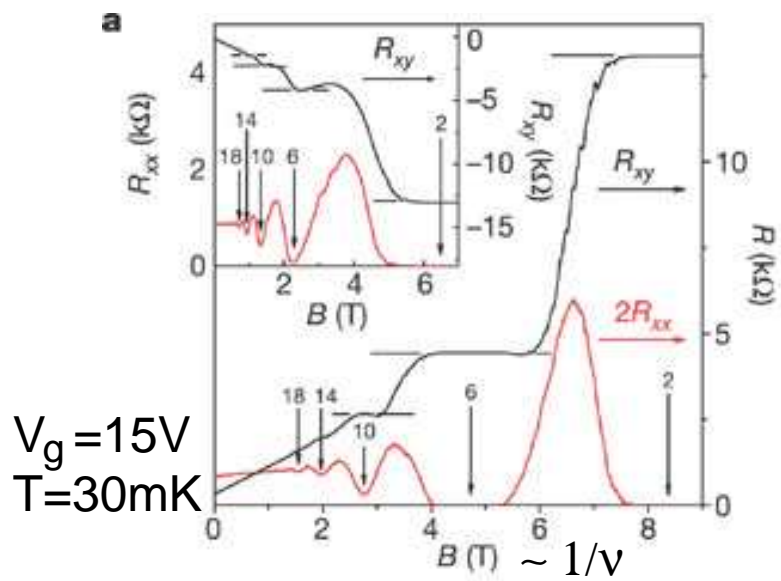
- Quantum Hall effect at  $\nu = \pm 2, \pm 6, \pm 10, \dots$



# IQHE in graphene

Novoselov et al., Nature 438, 197 (2005)

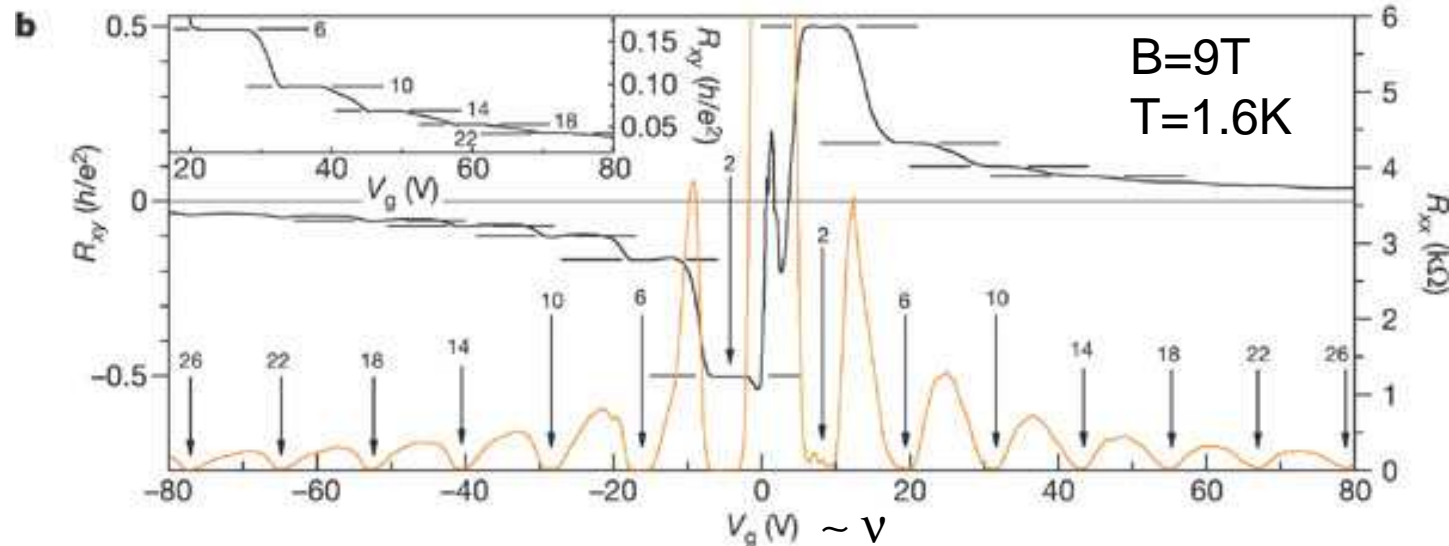
Zhang et al., Nature 438, 201 (2005)



Graphene IQHE:

$$R_H = h/e^2 \nu$$

$$\text{at } \nu = 2(2n+1)$$



Usual IQHE:

$$\text{at } \nu = 2n$$

(no Zeeman)

# Tilted cones in a strong magnetic field

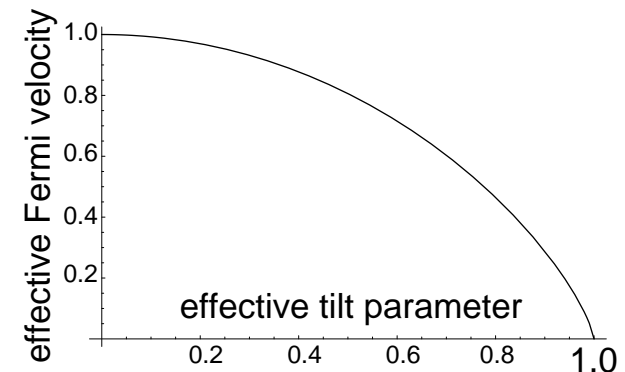
Motivation: How is the **Landau level spectrum** affected by the tilt?

$$H_\xi = \xi (\mathbf{w}_0 \cdot \mathbf{q} \mathbb{1} + w_x q_x \sigma^x + w_y q_y \sigma^y) \quad \tilde{w}_0 = \sqrt{\left(\frac{w_{0x}}{w_x}\right)^2 + \left(\frac{w_{0y}}{w_y}\right)^2}$$

⊕ Peierls substitution:  $\mathbf{q} \rightarrow \mathbf{q} + e\mathbf{A}(\mathbf{r})$  ⊕ semiclassics

⇒ **energy spectrum in  $\alpha$ -(BEDT-TTF) $_2$ I $_3$**  (as for graphene):

$$\epsilon_{\lambda,n} = \lambda \frac{v_F^*}{l_B} \sqrt{2n}$$



MOG, J.-N. Fuchs, F. Piéchon, G. Montambaux, PRB 78, 045415 (2008)

• effect of the tilt: **renormalisation**  $v_F^* = \sqrt{w_x w_y} (1 - \tilde{w}_0^2)^{3/4}$

Ⓢ Landau level  $n = 0$  requires **full quantum treatment** !

# Crossed magnetic and electric fields in graphene

graphene in crossed  $B \perp E$  fields Lukose et al. PRL 98, 116802 (2007)

- Lorentz boost into reference frame  
 $v_D = E/B < v_F$ :

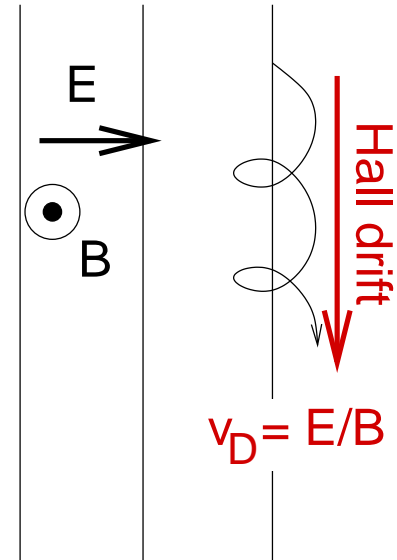
$$B \rightarrow B' = B \sqrt{1 - (E/v_F B)^2}$$

- energy in rest frame:

$$\epsilon' \propto 1/l'_B \propto \sqrt{B'}$$

$\Rightarrow$  energy in lab frame:

$$v_F \rightarrow v_F [1 - (E/v_F B)^2]^{3/4}$$



- “tilt”:

$$\tilde{\omega} = E/v_F B < 1$$

- magnetic regime  
 $\sim$  closed orbits

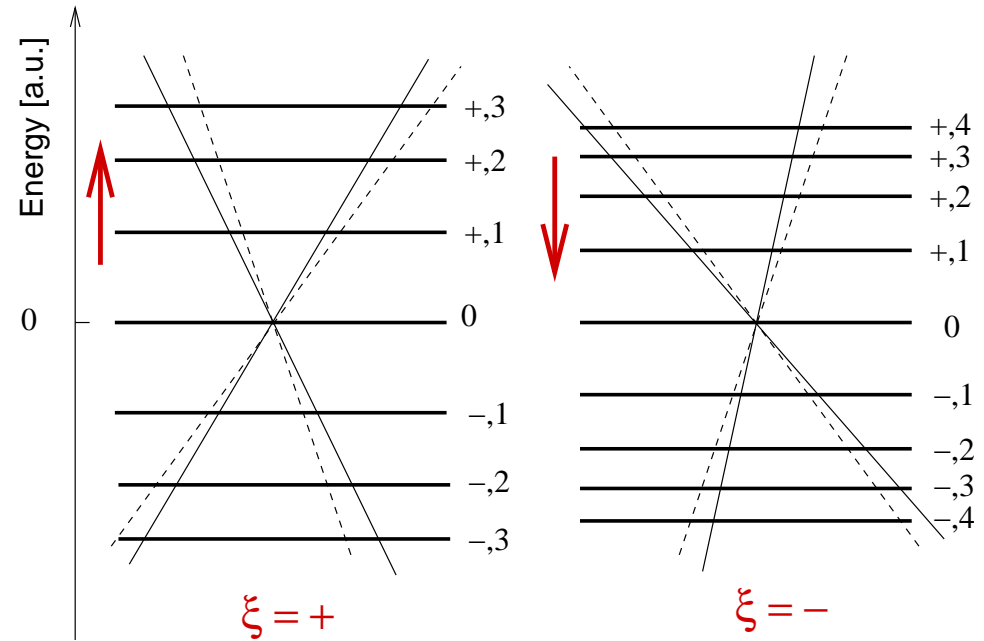
# Crossed magnetic and electric fields (tilted cones)

- inplane  $E$  field affects **tilt**:

$$\mathbf{w}_0 \rightarrow \mathbf{w}_\xi = \mathbf{w}_0 - \xi \frac{\mathbf{E} \times \mathbf{B}}{B^2}$$

⇒ new tilt parameter

$$\tilde{w}_\xi(E) = \sqrt{\frac{w_{\xi x}^2}{w_x^2} + \frac{w_{\xi y}^2}{w_y^2}}$$



Landau level spectrum depends on valley index  $\xi$  :

$$\epsilon_{\lambda, n; k}^\xi(E) = \lambda \frac{\sqrt{w_x w_y}}{l_B} [1 - \tilde{w}_\xi(E)^2]^{3/4} \sqrt{2n} + \frac{E}{B} k$$

# Possible experimental verification

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1. Quantum Hall measurement: (problematic)

lifted valley degeneracy  $\rightarrow$  additional plateaus

- no single-layer  $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub> !

$\Rightarrow$  field-effect doping may be inhomogeneous over layers

- in graphene: strong strain (10 – 20%) + large inplane electric field ( $\sim 10^6$  V/m)

$\Rightarrow$  maximal 1% effect

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- in graphene: strong strain (10 – 20%) + large inplane electric field ( $\sim 10^6$  V/m)

⇒ maximal 1% effect

## 2. Infrared transmission spectroscopy in $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>

- $\sim 10\%$  effect in doubled absorption lines

$$\Delta_n^\xi(E) = \frac{\sqrt{2w_x w_y}}{l_B} [1 - \tilde{w}_\xi(E)^2]^{3/4} (\sqrt{n} + \sqrt{n+1})$$

# LL quantisation in the vicinity of the topological PT

$$H' = \begin{pmatrix} 0 & \Delta + \frac{q_x^2}{2m^*} - icq_y \\ \Delta + \frac{q_x^2}{2m^*} + icq_y & 0 \end{pmatrix}$$

– in a magnetic field:

- semi-metal ( $m^* \Delta < 0$ ):

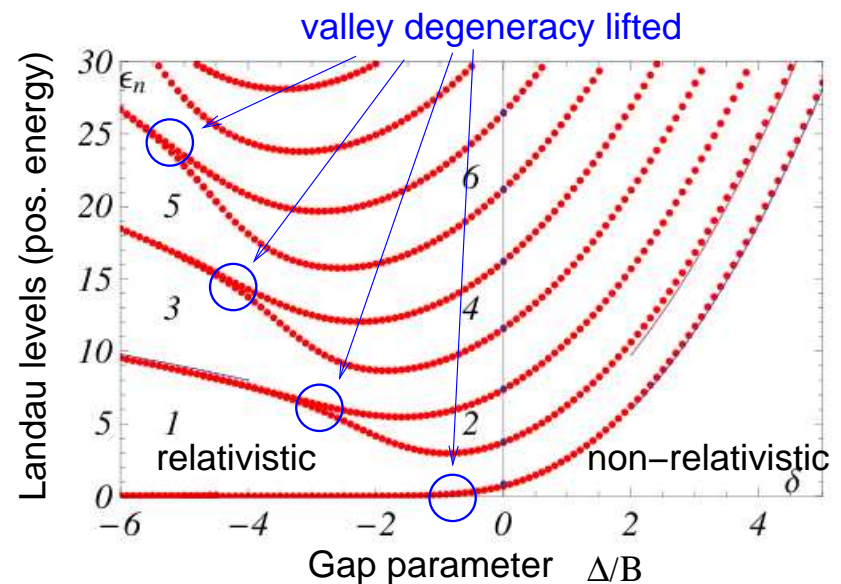
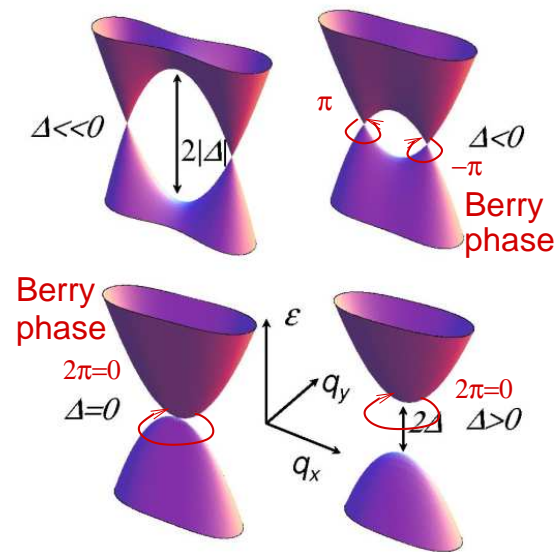
$$\epsilon_n \propto \pm \sqrt{nB}$$

- transition ( $\Delta = 0$ ):

$$\epsilon_n \propto \pm \left[ \left( n + \frac{1}{2} \right) B \right]^{2/3}$$

- insulator ( $m^* \Delta > 0$ ):

$$\epsilon_n \propto \pm \left[ \Delta + \# \left( n + \frac{1}{2} \right) B \right]$$





# Conclusions (I)

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Study of **tilted** Dirac cones in **distorted graphene** and  $\alpha$ -(BEDT-TTF)<sub>2</sub>I<sub>3</sub>

- model: generalised Weyl Hamiltonian

$$H = \mathbf{w}_0 \cdot \mathbf{q} \mathbb{1} + w_x q_x \sigma^x + w_y q_y \sigma^y$$

- Landau level spectrum: **decreased spacing** due to tilt
  - zero-energy Landau level survives the tilt
  - possible **valley degeneracy lifting** in crossed magnetic and electric fields
- ⇒ possible experimental verification in infrared-transmission spectroscopy

# Conclusions (II)

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## Dirac-point motion and topological (S)MIT

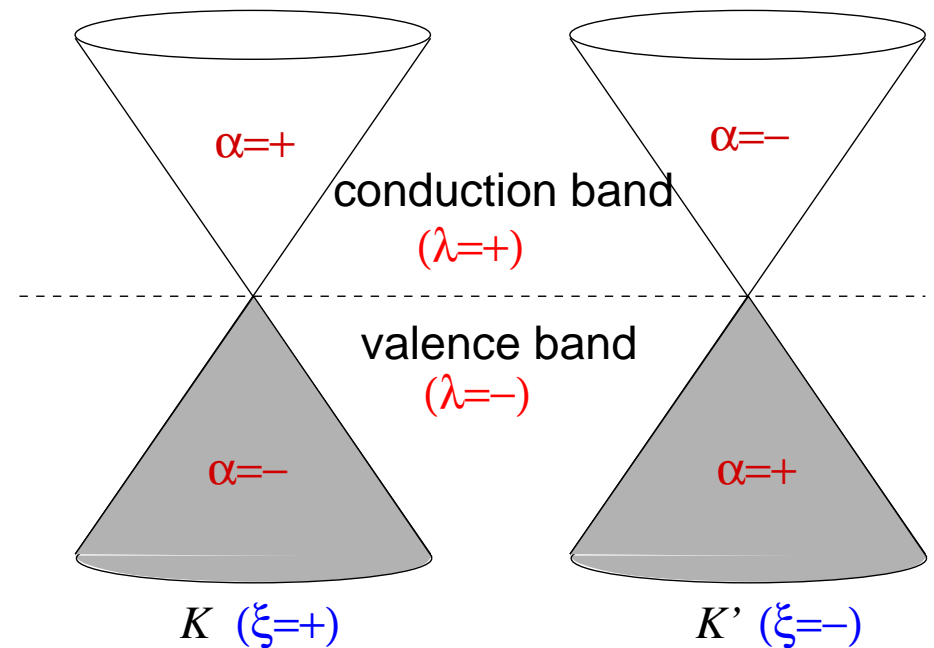
- model Hamiltonian (linear-quadratic)

$$H' = \begin{pmatrix} 0 & \Delta + \frac{q_x^2}{2m^*} - icq_y \\ \Delta + \frac{q_x^2}{2m^*} + icq_y & 0 \end{pmatrix}$$

- **topological transition** at  $\Delta = 0$  (Berry phase):  
change from  $\pm\pi$  around Dirac pts to 0 at merging pt
- particular LL quantisation
- possible experimental verification:
  - unphysical distortion in **graphene**
  - topological PT at  $\Gamma$ -point in  $\alpha$ -**(BEDT-TTF)<sub>2</sub>I<sub>3</sub>** ( $> 40$  kbar)
  - **cold atoms**

# Isospin quantum numbers

- valley isospin  $\xi = \pm$ : two-fold degeneracy
- band index  $\lambda = \pm$ : valence band (VB) or conduction band (CB)
- chirality  $\alpha = \boldsymbol{\sigma} \cdot \boldsymbol{\kappa} / |\boldsymbol{\kappa}| = \pm$  (sublattice spin projected on wave vector)
- (true spin  $s = \uparrow, \downarrow$ )



$$\text{band index} = \text{valley isospin} \times \text{chirality}$$

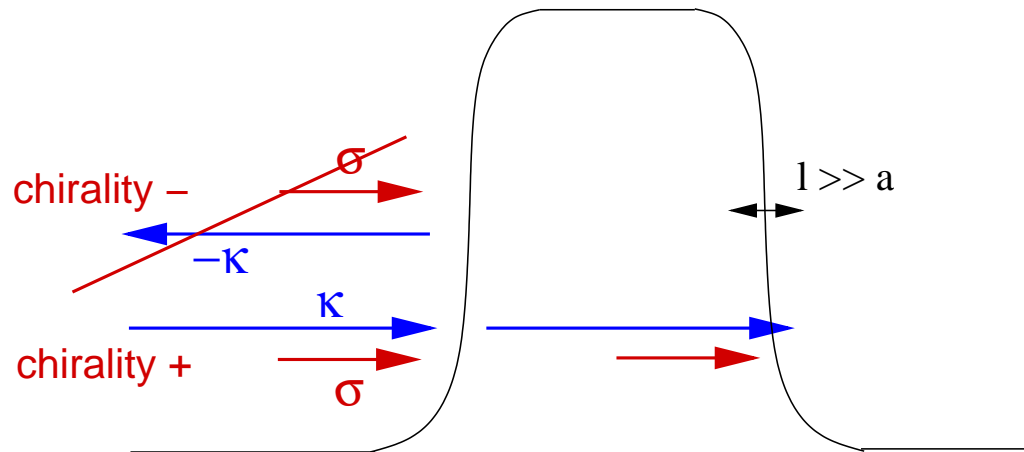
# Absence of backscattering – Klein tunneling

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Slowly varying obstacle (elastic scatterer):  $H_{diff} = V(\mathbf{r})\mathbb{1}$

⇒ no sublattice-isospin coupling

⇒ no valley coupling + elastic ⇒ **chirality conservation**



Chirality conservation ⇒ **absence of backscattering**

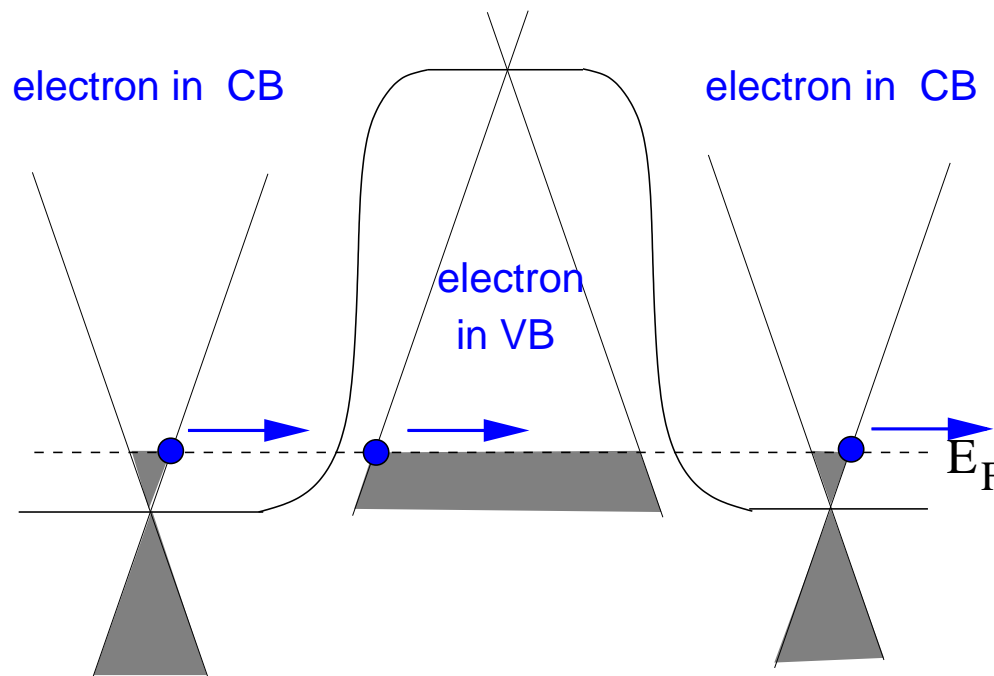
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**Klein tunneling** at a potential barrier vs. qm tunneling